Product data sheet

1. General description

The 74LV165A is an 8-bit parallel-load or serial-in shift register with complementary serial outputs (Q7 and $\overline{Q7}$) available from the last stage. When the parallel-load input (\overline{PL}) is LOW, parallel data from the inputs D0 to D7 are loaded into the register asynchronously. When input \overline{PL} is HIGH, data enters the register serially at the input DS. It shifts one place to the right (Q0 \rightarrow Q1 \rightarrow Q2, etc.) with each positive-going clock transition. This feature allows parallel-to-serial converter expansion by tying the output Q7 to the input DS of the succeeding stage.

The clock input is a gate-OR structure which allows one input to be used as an active LOW clock enable input (\overline{CE}) input. The pin assignment for the inputs CP and \overline{CE} is arbitrary and can be reversed for layout convenience. The LOW-to-HIGH transition of the input \overline{CE} should only take place while CP HIGH for predictable operation.

Schmitt-trigger action at all inputs, makes the circuit tolerant for slower input rise and fall times. It is fully specified for partial-power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the damaging current backflow through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 2.0 V to 5.5 V
- · Synchronous parallel-to-serial applications
- · Synchronous serial input for easy expansion
- Latch-up performance exceeds 250 mA
- CMOS LOW power consumption
- 5.5 V tolerant inputs/outputs
- Direct interface with TTL levels (2.7 V to 3.6 V)
- · Power-down mode
- · Complies with JEDEC standards:
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8B/JESD36 (2.7 V to 3.6 V)
 - JESD8-1A (4.5 V to 5.5 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C

3. Ordering information

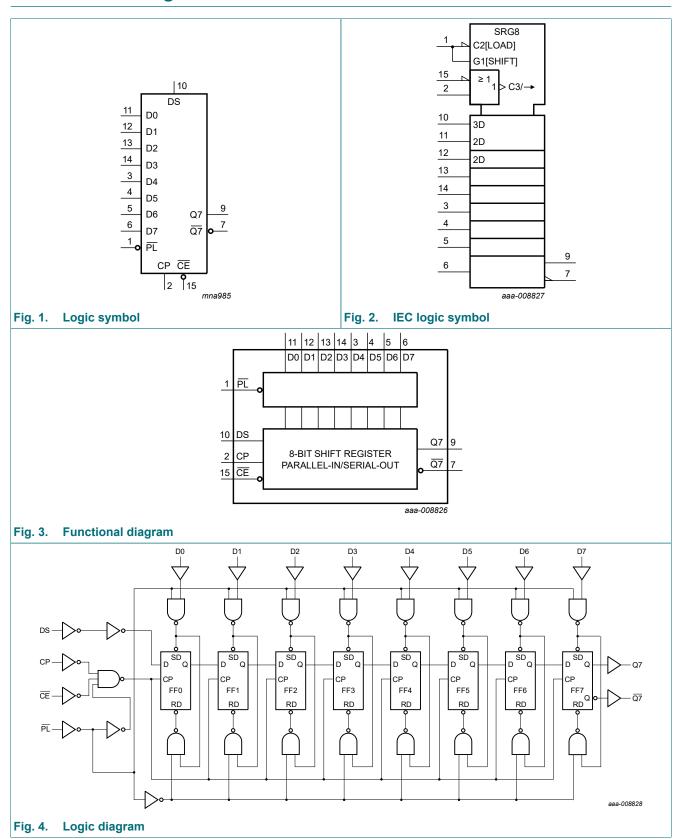
Table 1. Ordering information

Type number	Package						
	Temperature range	Name	Description	Version			
74LV165AD	-40 °C to +85 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1			
74LV165APW	-40 °C to +85 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1			



8-bit parallel-in/serial-out shift register

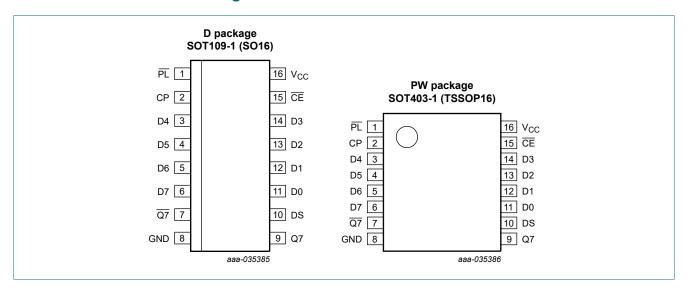
4. Functional diagram



8-bit parallel-in/serial-out shift register

5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description	
PL	1	parallel enable input (active LOW)	
СР	2	clock input (LOW-to-HIGH edge-triggered)	
Q7	7	complementary serial output from the last stage	
GND	8	ground (0 V)	
Q7	9	serial output from the last stage	
DS	10	serial data input	
D0 to D7	11, 12, 13, 14, 3, 4, 5, 6	parallel data inputs	
CE	15	clock enable input (active LOW)	
V _{CC}	16	positive supply voltage	

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6. Functional description

Table 3. Function table

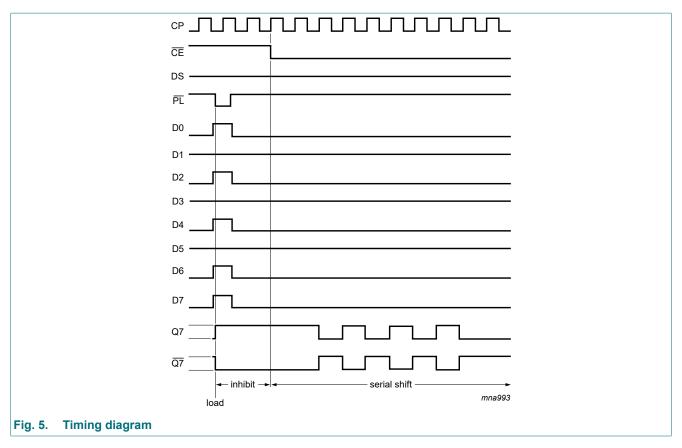
H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

q = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

 $X = don't care; \uparrow = LOW-to-HIGH clock transition.$

Operating modes	Input	Inputs				Qn re	Qn registers		Output	
	PL	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7	Q7	
parallel load	L	Х	Х	Х	L	L	L to L	L	Н	
	L	Х	Х	Х	Н	Н	H to H	Н	L	
serial shift	Н	L	1	I	Х	L	q0 to q5	q6	q6	
	Н	L	1	h	X	Н	q0 to q5	q6	q 6	
	Н	1	L	I	X	L	q0 to q5	q6	q6	
	Н	1	L	h	X	Н	q0 to q5	q6	q 6	
hold "do nothing"	Н	Н	Х	X	Х	q0	q1 to q6	q7	q7	
	Н	Х	Н	Х	X	q0	q1 to q6	q7	q7	



8-bit parallel-in/serial-out shift register

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V) [1]

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	V _I < 0 V	-	-20	mA
VI	input voltage		-0.5	+7	V
I _{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0$	-	±50	mA
Vo	output voltage		-0.5	V _{CC} + 0.5	V
		power-down mode	-0.5	+7	V
Io	output current	0 V < V _O < V _{CC}	-	±25	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +85 °C	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		2.0	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.3 V to 2.7 V	0	-	200	ns/V
		V _{CC} = 3.0 V to 3.6 V	0	-	100	ns/V
		V _{CC} = 4.5 V to 5.5 V	0	-	20	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		T _{amb} = -40 °C to +8		Unit
			Min	Тур	Max	
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 2.3 V to 2.7 V	0.7V _{CC}	-	-	V
		V _{CC} = 3.0 V to 3.6 V	0.7V _{CC}	-	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7V _{CC}	-	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 2.3 V to 2.7 V	-	-	$0.3V_{CC}$	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.3V _{CC}	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3V _{CC}	V

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Symbol	Parameter	Conditions	T _{amb} :	Unit		
			Min	Тур	Max	
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = -50 μA; V _{CC} = 2.0 V to 5.5 V	V _{CC} - 0.1	-	-	V
		I _O = -2.0 mA; V _{CC} = 2.3 V	2.0	-	-	V
		I _O = -6.0 mA; V _{CC} = 3.0 V	2.48	-	-	V
		I _O = -12 mA; V _{CC} = 4.5 V	3.8	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = 50 μA; V _{CC} = 2.0 V to 5.5 V	-	-	0.10	V
		I _O = 2.0 mA; V _{CC} = 2.3 V	-	-	0.40	V
		I_{O} = 6.0 mA; V_{CC} = 3.0 V	-	-	0.44	V
		I _O = 12 mA; V _{CC} = 4.5 V	-	-	0.55	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	±0.01	±1	μΑ
I _{OFF}	power-off leakage current	V _I or V _O = 5.5 V; V _{CC} = 0.0 V	-	±0.05	±5	μΑ
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	0.2	20	μΑ
C _I	input capacitance		-	3.0	-	pF

8-bit parallel-in/serial-out shift register

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND (ground = 0 V); for test circuit, see Fig. 11

Symbol	Parameter	Conditions		T _{amb}	= -40 °C to +	85 °C	Unit
				Min	Typ[1]	Max	
t _{pd}	propagation delay	$\overline{\text{CE}}$, CP to Q7, $\overline{\text{Q7}}$; C _L = 15 pF; see $\overline{\text{Fig. 6}}$ and $\overline{\text{Fig. 7}}$	[2]				
		V _{CC} = 2.3 V to 2.7 V	[3]	1.0	11.0	22.0	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	1.0	7.5	18.0	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	1.0	5.5	11.5	ns
		\overline{PL} to Q7, $\overline{Q7}$; $C_L = 15 \text{ pF}$; see $\overline{Fig. 7}$					
		V _{CC} = 2.3 V to 2.7 V	[3]	1.0	11.5	23.5	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	1.0	8.0	18.5	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	1.0	5.5	11.5	ns
		D7 to Q7, Q7; C _L = 15 pF; see <u>Fig. 8</u>					
		V _{CC} = 2.3 V to 2.7 V	[3]	1.0	12.0	24.0	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	1.0	8.5	16.5	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	1.0	6.0	10.5	ns
		CE, CP to Q7, Q7; see Fig. 6 and Fig. 7					
		V _{CC} = 2.3 V to 2.7 V	[3]	1.0	13.0	26.0	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	1.0	9.0	21.5	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	1.0	6.1	13.5	ns
		PL to Q7, Q7; see Fig. 7					+
		V _{CC} = 2.3 V to 2.7 V	[3]	1.0	14.0	28.0	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	1.0	10.0	22.0	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	1.0	6.5	13.5	ns
		D7 to Q7, Q7; see Fig. 8					+
		V _{CC} = 2.3 V to 2.7 V	[3]	1.0	14.0	28.0	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	1.0	10.0	20	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	1.0	6.5	12.5	ns
W	pulse width	CP input HIGH to LOW; see Fig. 6					
		V _{CC} = 2.3 V to 2.7 V	[3]	9.0	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	7.0	-	-	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	4.0	-	-	ns
		PL input LOW; see Fig. 7					
		V _{CC} = 2.3 V to 2.7 V	[3]	13.0	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	9.0	-	-	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	6.0	-	-	ns
rec	recovery time	PL to CP, CE; see Fig. 7					+
		V _{CC} = 2.3 V to 2.7 V	[3]	8.5	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	6.0	-	-	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	4.0	-	_	ns

8-bit parallel-in/serial-out shift register

Symbol	Parameter	Conditions		T _{amb}	= -40 °C to +	85 °C	Unit
				Min	Typ[1]	Max	
t _{su}	set-up time	DS to CP, CE; see Fig. 9					
		V _{CC} = 2.3 V to 2.7 V	[3]	6.0	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	4.0	-	-	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	7.0	-	-	ns
		CE to CP, CP to CE; see Fig. 9					
		V _{CC} = 2.3 V to 2.7 V	[3]	7.0	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	5.0	-	-	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	3.5	-	-	ns
		D7 to PL; see Fig. 10					
		V _{CC} = 2.3 V to 2.7 V	[3]	12	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	8.5	-	-	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	5.0	-	-	ns
t _h	hold time	DS to CP, CE; PL to CP, CE; see Fig. 9					
		V _{CC} = 2.3 V to 2.7 V	[3]	0	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	0	-	-	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	0.5	-	-	ns
		Dn to PL; see Fig. 10					
		V _{CC} = 2.3 V to 2.7 V	[3]	0.5	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[4]	0.5	-	-	ns
		V _{CC} = 4.5 V to 5.5 V	[5]	1.0	-	-	ns
f _{max}	maximum	CP input; C _L = 15 pF; see Fig. 6					
	frequency	V _{CC} = 2.3 V to 2.7 V	[3]	45	80	-	MHz
		V _{CC} = 3.0 V to 3.6 V	[4]	50	115	-	MHz
		V _{CC} = 4.5 V to 5.5 V	[5]	90	165	-	MHz
		CP input; see Fig. 6					
		V _{CC} = 2.3 V to 2.7 V	[3]	35	65	-	MHz
		V _{CC} = 3.0 V to 3.6 V	[4]	50	90	-	MHz
		V _{CC} = 4.5 V to 5.5 V	[5]	85	125	-	MHz
C _{PD}	power dissipation capacitance	V_I = GND to V_{CC} ; V_{CC} = 3.3 V	[6]	-	24	-	pF

- [1] Typical values are measured at T_{amb} = 25 °C and nominal V_{CC} .
- [2]
- t_{pd} is the same as t_{PHL} and t_{PLH} . Typical values are measured at V_{CC} = 2.5 V. [3]
- [4]
- Typical values are measured at V_{CC} = 3.3 V. Typical values are measured at V_{CC} = 5.0 V. [5]
- [6] C_{PD} is used to determine the dynamic power dissipation $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ (P_D in μ W), where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

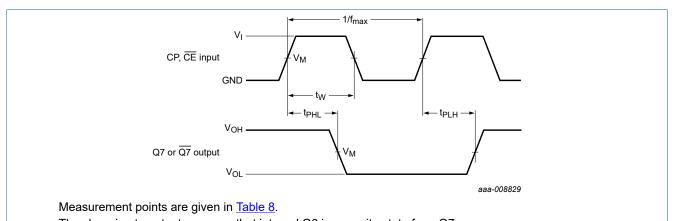
 $\Sigma(C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs};$

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V.

8-bit parallel-in/serial-out shift register

10.1. Waveforms and test circuit



The changing to output assumes that internal Q6 is opposite state from Q7.

Fig. 6. Clock pulse (CP) and clock enable (CE) to output (Q7 or Q7) propagation delays, clock pulse width and maximum clock frequency

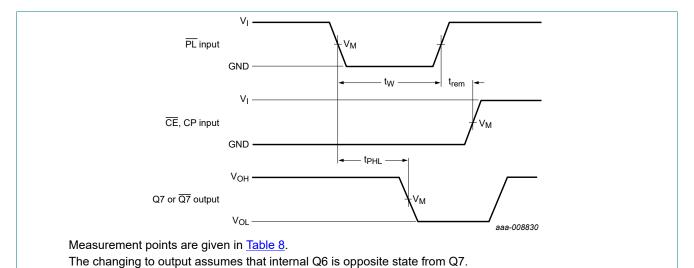
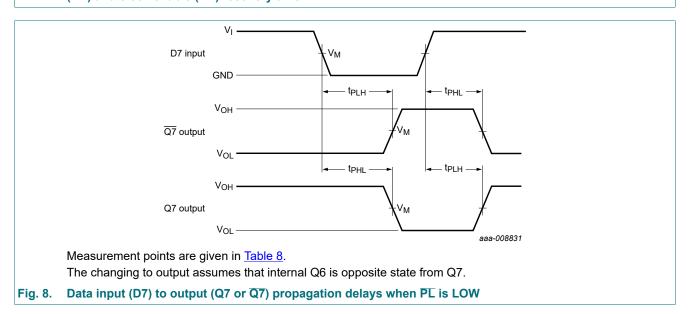
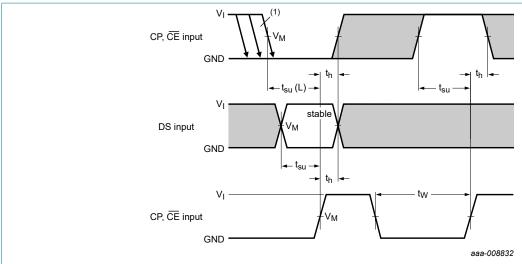


Fig. 7. Parallel load (PL) pulse width, parallel load to output (Q7 or Q7) propagation delays, parallel load to clock (CP) and clock enable (CE) recovery time



Product data sheet

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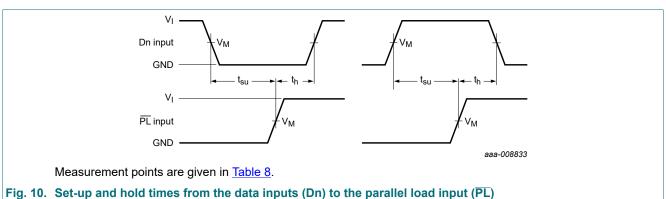


Measurement points are given in Table 8.

(1) CE may change only from HIGH-to-LOW while CP is LOW.

The shaded areas indicate when the input is permitted to change for predictable output performance.

Fig. 9. Set-up and hold times

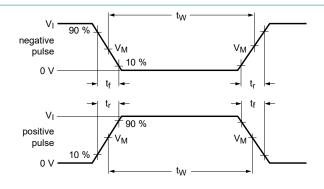


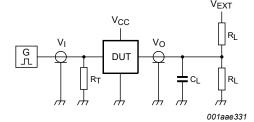
rig. 10. Set-up and field times from the data inputs (bil) to the parallel load input (FL

Table 8. Measurement points

Supply voltage	Input	Output
V _{CC}	V _M	V _M
2.0 V to 5.5 V	0.5 × V _{CC}	0.5 × V _{CC}

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Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance;

 C_L = Load capacitance including jig and probe capacitance;

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator;

 V_{EXT} = External voltage for measuring switching times.

Fig. 11. Test circuit for measuring switching times

Table 9. Test data

Supply voltage	Input		Load		V _{EXT}	
	V _I	t _r , t _f	CL	R_L	t _{PHL} , t _{PLH}	
2.0 V to 5.5 V	V _{CC}	3.0 ns	50 pF, 15 pF	1 kΩ	open	

8-bit parallel-in/serial-out shift register

11. Package outline

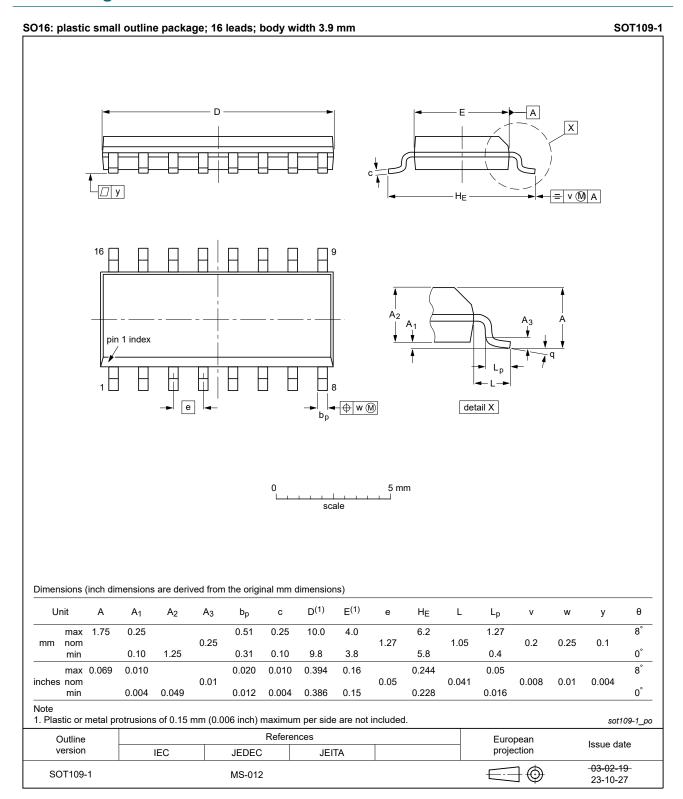


Fig. 12. Package outline SOT109-1 (SO16)

8-bit parallel-in/serial-out shift register

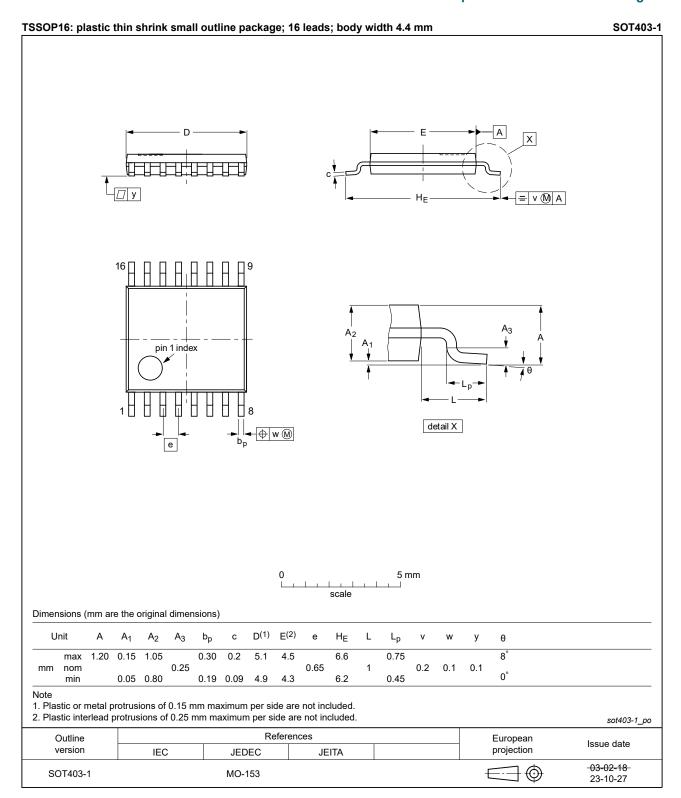


Fig. 13. Package outline SOT403-1 (TSSOP16)

8-bit parallel-in/serial-out shift register

12. Abbreviations

Table 10. Abbreviations

Acronym	Description	
CDM	Charged Device Model	
CMOS	nplementary Metal-Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
HBM	Human Body Model	
TTL	ansistor-Transistor Logic	

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74LV165A v.5	20240418	Product data sheet	-	74LV165A v.4	
Modifications:	 Section 2: ESD specification updated according to the latest JEDEC standard. Fig. 12, Fig. 13: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153 				
74LV165A v.4	20140328	Product data sheet	-	74LV165A v.3	
Modifications:	Minimum limit V _{OH} for V _{CC} = 4.5 V corrected from 3.0 V to 3.8 V (errata) in <u>Table 6</u>				
74LV165A v.3	20140220	Product data sheet	-	74LV165A v.2	
Modifications:	Typo corrected in <u>Table 2</u>				
74LV165A v.2	20130904	Product data sheet	-	74LV165A_CNV_1	
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. Family data added, see <u>Section 9</u> 				
74LV165A v.1	December 1990	Product specification	-	-	

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14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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8-bit parallel-in/serial-out shift register

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